TERMINATION CHIP 50 WATT



EN 13-3453

SHEET 1 OF 2 **DATA SHEET PART SERIES: 82-3012** Dwg 82-3012

FEATURES

APPLICATIONS

Mobile Networks Wide Band Operation High Power Broadcast

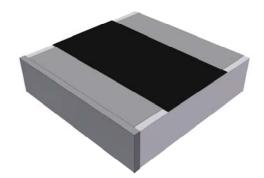
Direct Attached High Power Amplifiers

Low VSWR Isolators Military Easy Installation

Instrumentation



EMC Technology offers the widest selection of chip terminations worldwide. Chip components are offered in both thick and thin film resistive material and available in Alumina, Aluminum Nitride, Beryllium Oxide and CVD Diamond.



ORDERING INFORMATION

Part Identifier: 82-3012

SPECIFICATIONS

1.0 ELECTRICAL

Nominal Impedance: 50 ohms Frequency Range: DC - 2.0 GHz

VSWR: DC - 1.0 GHz 1.20:1 Max

1.0 - 2.0 GHz 1.35:1 Max

Input Power CW: 50 Watts @ 100°C heat sink, derated linearly to zero power and 150°C

Peak Power: 500 Watts (based on 10us pulse width and 1% duty cycle)

DC Resistance: 50 Ω ±5%

2.0 ENVIRONMENTAL

Operating Temperature: -55°C to +150°C Non-operating Temperature: -65°C to +150°C Temperature Coefficient: +/-200 PPM / °C max

3.0 MARKING

Unit Marking: No Marking

4.0 QUALITY ASSURANCE

Visual and Mechanical Inspection: Per 824W107

DC Resistance Check: 100% DC Resistance Check

Data Retention: Standard

5.0 PACKAGING

Standard Packaging: Tape and Reel

smiths microwave

Form 423F103 Rev-

Cage Codes: 24602 / 2Y194 Specifications are Subject to Change Without Notice

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Dwg 82-3012

T 2 OF 2 E 82-3012

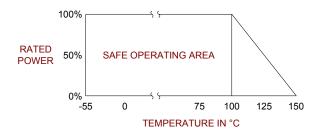
EN 13-3453 -Revision

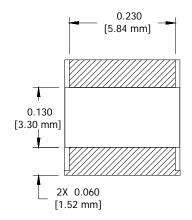
6.0 MECHANICAL

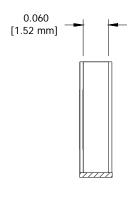
Substrate Material: Beryllium Oxide

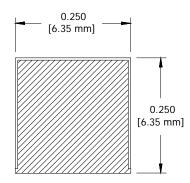
Resistive Film: Thin Film Terminal Material: Tin/Lead

Metric Dimensions: Provided for reference only









Unless Otherwise Specified: TOLERANCE: $X.XX = \pm 0.02$ $X.XXX = \pm 0.010$